

Description

- High speed switching application.
- Analog switch application.

Features

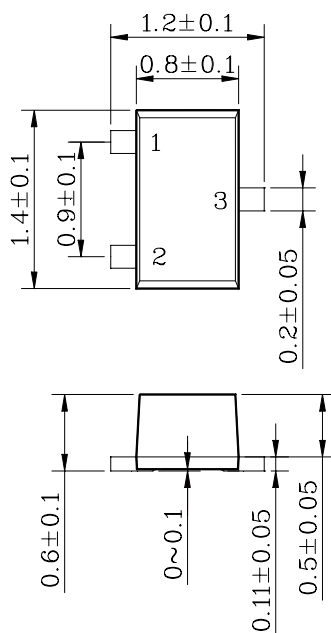
- -2.5V Gate drive.
- Low threshold voltage : $V_{th} = -0.5 \sim -1.5V$.
- High speed.

Ordering Information

Type NO.	Marking	Package Code
STJ828K	J9	SOT-623F

Outline Dimensions

unit : mm



PIN Connections

1. Gate
2. Source
3. Drain

Absolute maximum ratings

(Ta=25°C)

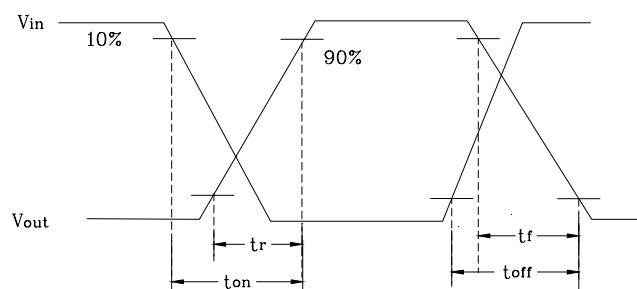
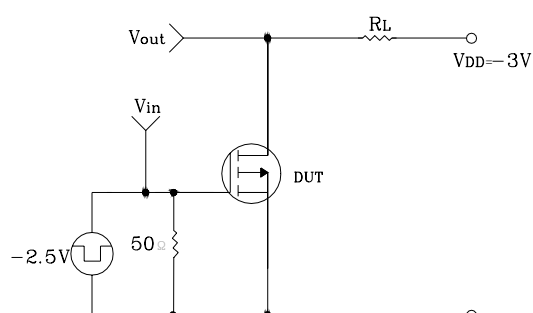
Characteristic	Symbol	Ratings	Unit
Drain-Source voltage	V_{DS}	-20	V
Gate-Source voltage	V_{GSS}	± 7	V
DC Drain current	I_D	-50	mA
Drain Power dissipation	P_D	100	mW
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55~150	°C

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Drain-Source breakdown voltage	BV_{DSS}	$I_D = -100\mu A, V_{GS} = 0$	-20			V
Gate-Threshold voltage	V_{th}	$I_D = -0.1mA, V_{DS} = -3V$	-0.5		-1.5	V
Drain cut-off current	I_{DSS}	$V_{DS} = -20V, V_{GS} = 0$			-1	μA
Gate leakage current	I_{GSS}	$V_{GS} = \pm 7V, V_{DS} = 0$			± 1	μA
Drain-Source on-resistance	$R_{DS(ON)}$	$V_{GS} = -2.5V, I_D = -10mA$			40	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3V, I_D = -10mA$	15			mS
Input capacitance	C_{iss}	$V_{DS} = -3V, V_{GS} = 0, f = 1MHz$		10.4		pF
Output capacitance	C_{oss}	$V_{DS} = -3V, V_{GS} = 0, f = 1MHz$		8.4		pF
Reverse Transfer capacitance	C_{rss}	$V_{DS} = -3V, V_{GS} = 0, f = 1MHz$		2.8		pF
Turn-on time	t_{ON}	$V_{DD} = -3V, I_D = -10mA$ $V_{GEN} = 0 \sim -2.5V$		0.15		μs
Turn-off time	t_{OFF}	$V_{DD} = -3V, I_D = -10mA$ $V_{GEN} = 0 \sim -2.5V$		0.13		μs

*. Switching Time Test Circuit



Electrical Characteristic Curves

Fig1 $I_D - V_{DS}$

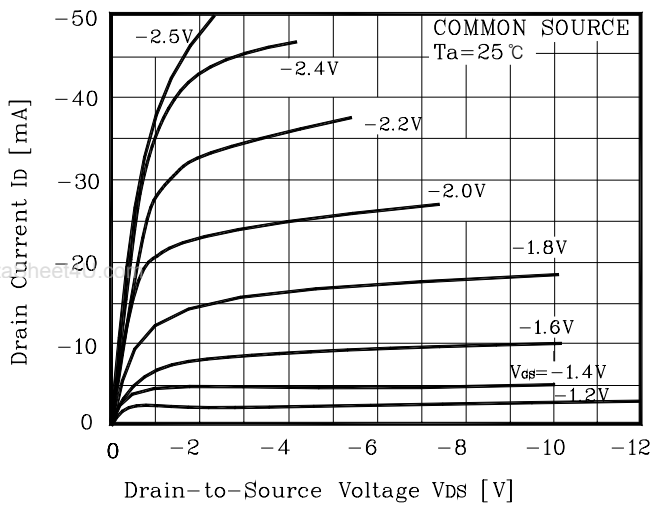


Fig2 $I_D - V_{DS}$

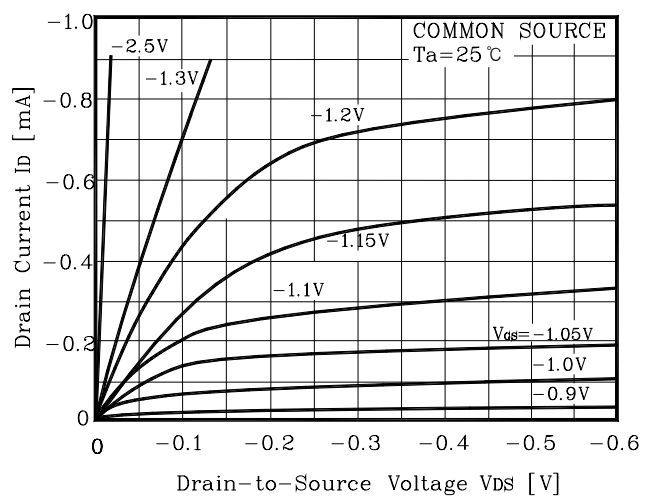


Fig3 $I_{DR} - V_{DS}$

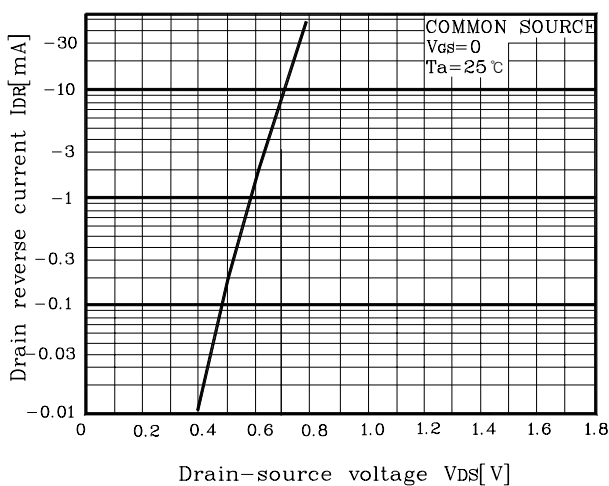


Fig4 $I_D - V_{GS}$

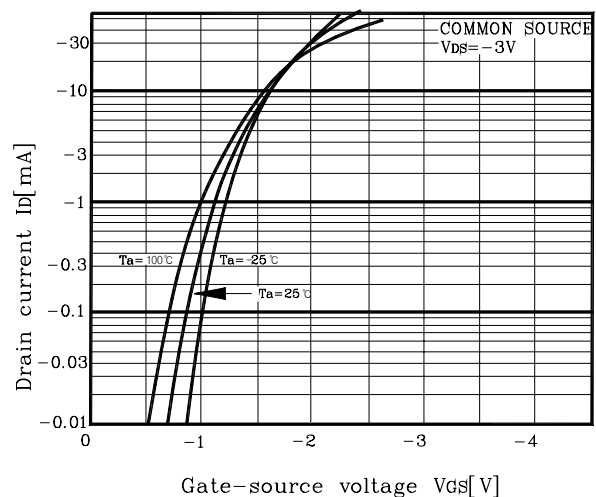


Fig5 $|Y_{fs}| - I_D$

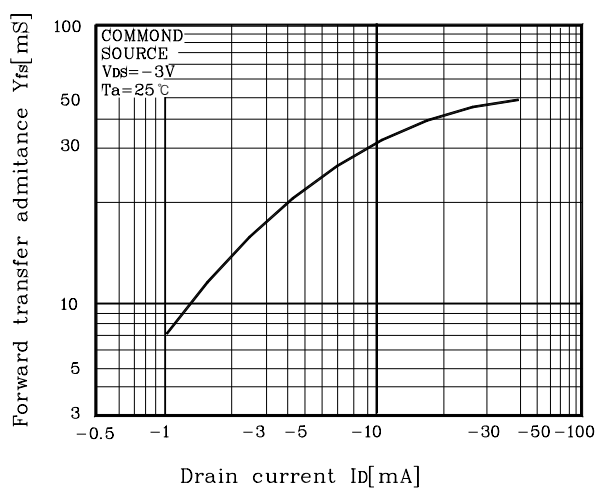


Fig6 C - VDS

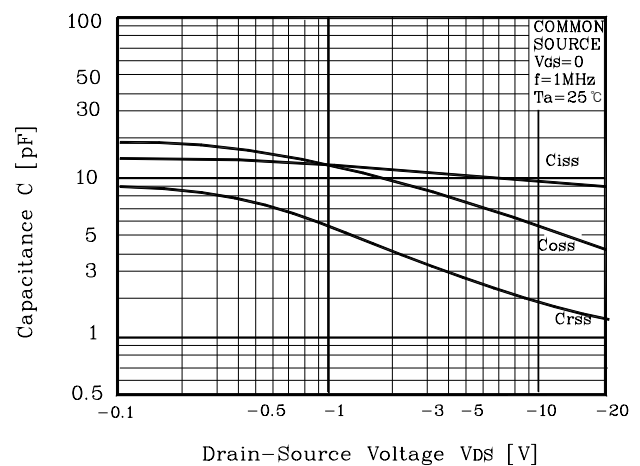


Fig7 $V_{DS(on)} - I_D$

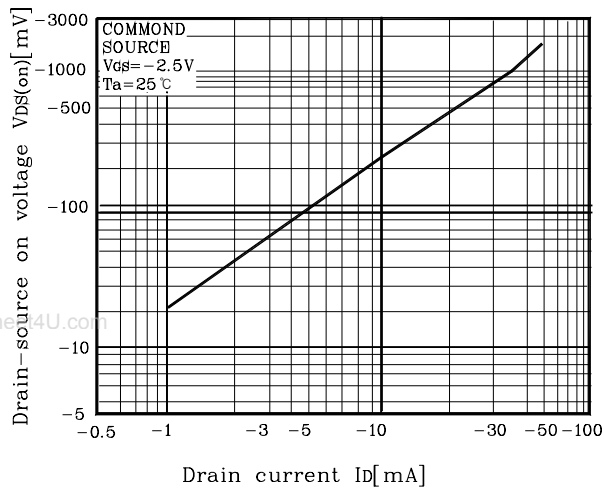


Fig8 $t - I_D$

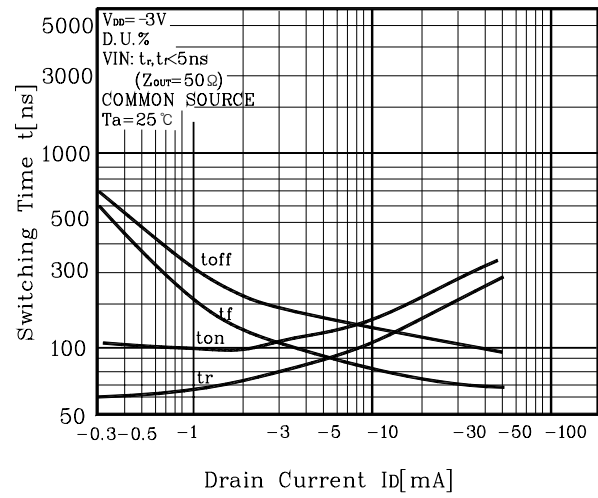


Fig9 $P_D - T_a$

